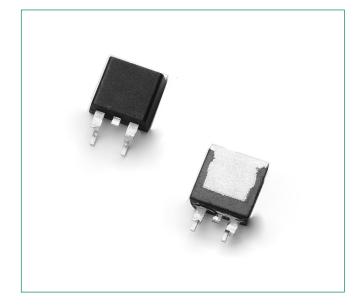


Pin Out

Thyristors

Surface Mount – 400V - 800V > MCR12DCM, MCR12DCN

MCR12DCM, MCR12DCN



Description

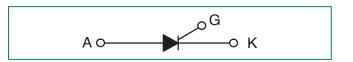
Designed primarily for half-wave ac control applications, such as motor controls, heating controls, and power supplies; or wherever half-wave, silicon gate-controlled devices are needed.

Features

- Small Size
- Passivated Die for Reliability and Uniformity
- Low Level Triggering and Holding Characteristics
- Epoxy Meets UL 94 V-0 @ 0.125 in
- ESD Ratings: Human Body Model, 3B > 8000 V Machine Model, C > 400 V
- Pb-Free Packages are Available

Functional Diagram

Datasheet









P0



3



Surface Mount - 400V - 800V > MCR12DCM, MCR12DCN

Maximum Ratings ($T_{J} = 25^{\circ}C$ unless otherwise noted)

Rating	Symbol	Value	Unit
Peak Repetitive Off–State Voltage (Note 1) (– 40 to 110°C, Sine Wave, 50 to 60 Hz, Gate Open) MCR12DCM MCR12DCN	V _{drm} , V _{rrm}	600 800	V
On-State RMS Current (180° Conduction Angles; $T_c = 90°$ C)	I _{T (RMS)}	12	А
Average On–State Current (180° Conduction Angles; $T_c = 90$ °C)	I _{t(AV)}	7.8	А
Peak Non-Repetitive Surge Current (1/2 Cycle, Sine Wave 60 Hz, T _J = 125°C)	I _{TSM}	100	А
Circuit Fusing Consideration (t = 8.3 ms)	l²t	41	A ² sec
Forward Peak Gate Power (Pulse Width \leq 10 µsec,T _c = 90°C)	P _{GM}	5.0	W
Forward Average Gate Power (t = 8.3 msec, $T_c = 90^{\circ}C$)	P _{gm (AV)}	0.5	W
Forward Peak Gate Current (Pulse Width \leq 1.0 µsec, T _c = 90°C)	I _{GM}	2.0	А
Operating Junction Temperature Range	TJ	-40 to 110	°C
Storage Temperature Range	T _{stg}	-40 to 150	°C

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

1. V_{DBM} and V_{RBM} for all types can be applied on a continuous basis. Ratings apply for zero or negative gate voltage; however, positive gate voltage shall not be applied concurrent with negative potential on the anode. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

Thermal Characteristics

Rating	Symbol	Value	Unit
Thermal Resistance, Junction-to-Case	R _{sJC}	2.2	
Thermal Resistance, Junction-to-Ambient	R _{8JA}	88	°C/W
Thermal Resistance, Junction-to-Ambient (Note 2)	R _{8JA}	80	
Maximum Lead Temperature for Soldering Purposes 1/8" from Case for 10 Seconds	TL	260	°C

Electrical Characteristics \cdot **OFF** (T₁ = 25°C unless otherwise noted)

Characteristic		Symbol	Min	Тур	Max	Unit
Peak Repetitive Forward or Reverse Blocking Current ($V_{AK} = Rated V_{DRM}$ or V_{RRM} , Gate Open)	$T_J = 25^{\circ}C$	I _{drm} ,	-	-	0.01	mA
(V _{AK} – Hated V _{DRM} OF V _{RRM} , Gate Open)	T _J = 125°C	I _{RRM}	-	-	5.0	ШA

Electrical Characteristics - **ON** ($T_J = 25^{\circ}$ C unless otherwise noted; Electricals apply in both directions)

Characteristic		Symbol	Min	Тур	Max	Unit
Peak Forward On–State Voltage (Note 2) (I $_{TM}$ = 16 A)		V _{TM}	-	1.3	1.9	V
Gate Trigger Current (Continuous dc)	$T_J = 25^{\circ}C$		0.5	0.65	1.0	mA
$(V_{D} = 12 \text{ V}; \text{ R}_{L} = 100 \Omega)$	$T_J = -40^{\circ}C$	GT	-	-	2.0	ШA
Gate Trigger Voltage (Continuous dc) $V_{\rm c} = 12 V R_{\rm c} = 100 Q$	T _J = 25°C	V	0.3	0.65	1.0	V
$(V_{D} = 12 \text{ V}, \text{ R}_{L} = 100 \Omega)$	$T_J = -40^{\circ}C$	V _{GT}	-	-	1.5	V
Gate Non-Trigger Voltage ($V_D = 12 V, R_L = 100 \Omega$)	T _J = 125°C	tgt	0.2	-	-	V
Holding Current	$T_{J} = 25^{\circ}C$		4.0	22	40	mA
(V _D = 12 V, Gate Open, Initiating Current = 200 mA)	$T_{J} = -40^{\circ}C$	H H	-	-	80	
Latch Current $(V_{D} = 12 \text{ V}, \text{ I}_{G} = 20 \mu$	A, T _J = 25°C)		4.0	22	40	mA
$(V_{_{ m D}}$ = 12 V, I $_{_{ m G}}$ = 40 μ	A, T _J = -40°C)		_	_	80	

Dynamic Characteristics						
Characteristic	Symbol	Min	Тур	Max	Unit	
Critical Rate of Rise of Off–State Voltage ($V_D = Rated V_{DRM}$, Exponential Waveform, Gate Open, $T_J = 125^{\circ}C$)	dv/dt	50	200	_	V/µs	

2. These ratings are applicable when surface mounted on the minimum pad sizes recommended.

3. 1/8" from case for 10 seconds.

4. Pulse Test: Pulse Width ≤ 2.0 msec, Duty Cycle $\leq 2\%.$



Surface Mount – 400V - 800V > MCR12DCM, MCR12DCN

Voltage Current Characteristic of SCR

Symbol	Parameter
V _{drm}	Peak Repetitive Forward Off State Voltage
I _{DRM}	Peak Forward Blocking Current
V _{RRM}	Peak Repetitive Reverse Off State Voltage
I _{RRM}	Peak Reverse Blocking Current
V _{TM}	Maximum On State Voltage
I _H	Holding Current

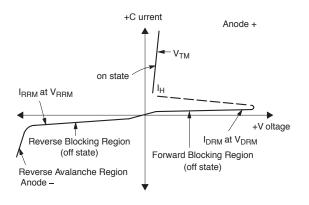
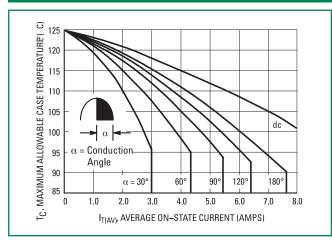


Figure 1. Average RMS Current Derating



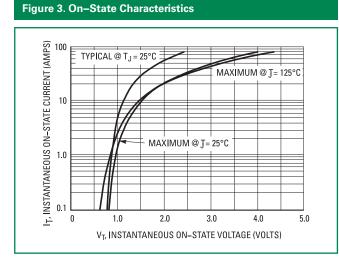


Figure 2. On–State Power Dissipation

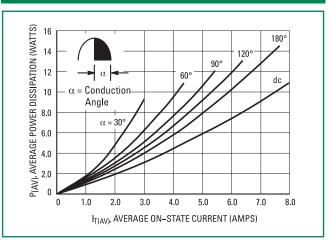
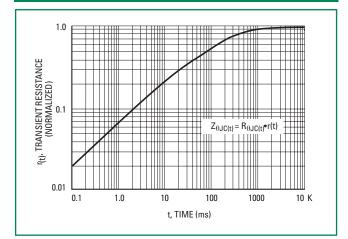


Figure 4. Transient Thermal Response





Surface Mount - 400V - 800V > MCR12DCM, MCR12DCN

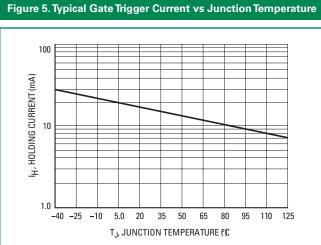


Figure 6. Typical Gate Trigger Voltage vs Junction Temperature

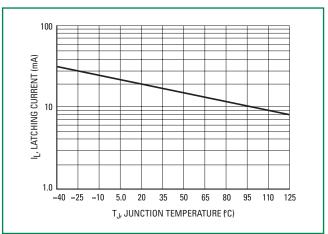
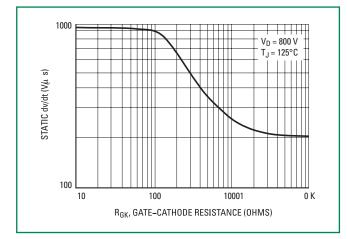


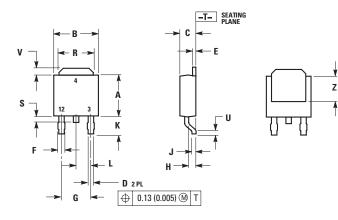
Figure 7. Typical Holding Current vs Junction Temperature



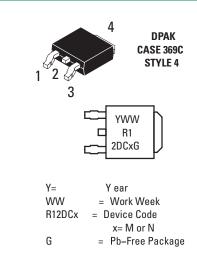


Surface Mount – 400V - 800V > MCR12DCM, MCR12DCN

Dimensions



Part Marking System



Pin Assignment	
1	Cathode
2	Anode
3	Gate
4	Anode

Ordering Information					
Device	Package	Shipping			
MCR12DCMT4	DPAK				
MCR12DCMT4G	DPAK (Pb–Free)	2500 /			
MCR12DCNT4	DPAK	Tape & Reel			
MCR12DCNT4G	TO-220AB (Pb-Free)				

D .	Incl	nes	Millim	neters
Dim	Min	Max	Min	Max
А	0.235	0.245	5.97	6.22
В	0.250	0.265	6.35	6.73
С	0.086	0.094	2.19	2.38
D	0.027	0.035	0.69	0.88
E	0.018	0.023	0.46	0.58
F	0.037	0.045	0.94	1.14
G	0.180 BSC		4.58 BSC	
Н	0.034	0.040	0.87	1.01
J	0.018	0.023	0.46	0.58
К	0.102	0.114	2.60	2.89
L	0.090 BSC		2.29 BSC	
R	0.180	0.215	4.57	5.45
S	0.025	0.040	0.63	1.01
U	0.020		0.51	
V	0.035	0.050	0.89	1.27
Z	0.155		3.93	

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

2. CONTROLLING DIMENSION: INCH.

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